

AM Receiver Circuit

Technology: Bipolar

Features

- Controlled RF preamplifier
- Multiplicative balanced mixer
- Separate oscillator with amplitude control
- IF amplifier with gain control

- Balanced full-wave detector
- Audio preamplifier
- Internal AGC voltage
- Amplifier for field-strength indication
- Electronic stand-by on/off switch

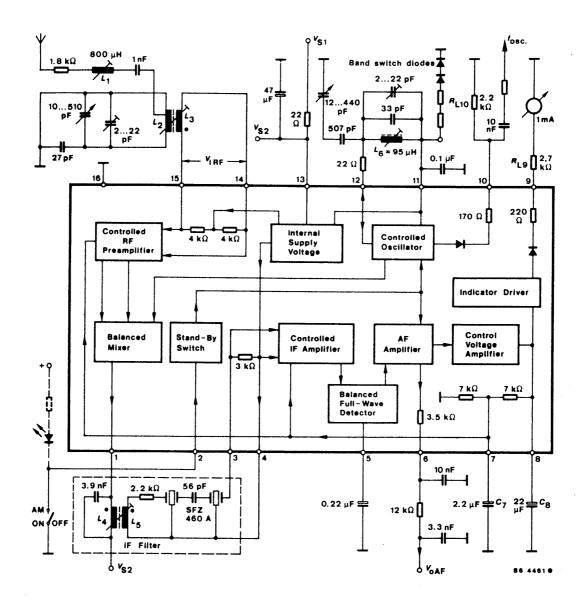


Figure 1. Block diagram and application circuit

Absolute Maximum Ratings

Reference point pin 16, unless otherwise specified

Parameters		Symbol	Value	Unit
Supply voltage	Pin 13	Vs	20	V
Voltage on Pin 2		V ₂	0 to 20	V
RF inputs Voltages				
Reference point 15	Pin 14 Pin 14 Pin 14 Pin 15 Pin 15	$ \begin{vmatrix} \pm V_{i \ 14/15} \\ V_{i} \\ -V_{i} \\ V_{i} \\ -V_{i} \end{vmatrix} $	$12 \\ V_s \\ 0.6 \\ V_i \\ 0.6$	V V V V V
RF inputs Currents	Pin 14, 15	±Ii	200	mA
Ambient temperature range		T _{amb}	- 30 to + 80	°C
Storage temperature range		T _{stg}	- 55 to + 150	°C

Electrical Characteristics

 V_S = 8.5 V, reference point Pin 16, f_{IRF} = 1MHz, R_G = 50 Ω , f_{mod} = 0.4 kHz, m = 30%, f_{IF} = 460 kHz, T_{amb} = +25°C, unless otherwise specified

Parameters	Test Conditions / Pin		Symbol	Min	Туре	Max	Unit
Supply voltage range		Pin 13	Vs	7.5		18	V
Supply current	Without load, $I_L = 0$ (Pin 11)	Pin 13	I _S		23	30	mA
RF preamplifier and mixe	r						
DC input voltages		Pin 14, 15	Vi		V _S /2		V
Input impedances	$V_{iRF} < 300 \ \mu V,$ $V_{iRF} > 10 \ mV,$	Pin 14,15 Pin 14, 15	R _i C _i R _i		5.5 25 8.0		kΩ pF kΩ
	$v_{1RF} > 10 \text{ m/v},$	1 111 14, 15	C _i		22		pF
Output impedance		Pin 1	R _O C _O	500	6.0		kΩ pF
Maximum conversion conductance	I _{O 1 IF} /V _{iRF}		ΔS_{M}			6.5	mA/V
Maximum IF output voltage		Pin 1	V _{OIF(PP)}			5.0	V
Output current		Pin 1	IO		1.2		mA
Preamplifier control range			SM		30		dB
Max. RF input voltage		Pin 14, 15	V _{i(PP)}			2.5	V
Oscillator							
Frequency range		Pin 12	f _{OSC}	0.6		60	MHz
Oscillator circuit impedance range		Pin 12	Z _{LOSC}	0.5		200	kΩ





Parameters	Test Conditions	s / Pin	Symbol	Min	Туре	Max	Unit
Controlled oscillator amplitude		Pin 12	V _{OSC}		130	150	mV
DC output voltage	$I_L = 0 V$	Pin 11	Vo		6 V _{BE(4V)}		V
Output load current range		Pin 11	$-I_L$			20	mA
Output resistance	$I_L = 5 \pm 0.5 \text{ mA},$	Pin 11	R _O		25		Ω
Oscillator frequency outp	ut	Pin 10					
Output voltage	$R_{L10} = 4.7 \ k\Omega$		V _{O(PP)}		320		mV
Output resistance			R _O		170		Ω
Allowable output current			I _{O(P)}			3	mA
IF amplifier an AF stage							
DC input voltages		Pin 3, 4	Vi		2		V
Input impedance		Pin 3	R _i C _i	2.4	3 7	3.9	kΩ pF
Max. IF input voltage	m = 80%, d = 3%	Pin	Vi		90		mV
Control range	$V_{0AF} = -6 dB$		ΔV_i		61		dB
Audio output voltage	$V_i = 1 \text{ mV}$ (Pin 3), without load	Pin 6	Vo		310		mV
Audio output resistance		Pin 6	R _O		3.5		kΩ
Field-strength indication		Pin 9					
DC indicator voltages	$\begin{array}{l} R_{L9}=2.7 \text{ k}\Omega,\\ V_i=0\\ V_i=500 \text{ mV} \end{array}$		V _O V _O	0 2.5	2.8	140 3.1	mV V
Output current capability			-I _O	2.0			mA
Output resistance	$-I_0 = 0.5 \text{ mA}$		R _O		220		Ω
Reverse voltage at the output	AM switch-off, $\pm I_0 \leq 1 \mu A$		Vo		6		v
Stand-by switch		Pin 2					
Switching voltage			Vi		2.75		V
Required control voltage	AM ON AM OFF		$\begin{array}{c} V_i \\ V_i^{(1)} \end{array}$	3.5		2	V
Input current	AM on, switching of AM off, reverse cu $(V_2 = V_3)$		$\stackrel{-I_i}{\pm I_i}$			200 10	μΑ

¹⁾ or open input

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Operating Conditions

 $V_S = 8.5 V$, $f_{iRF} = 1 MHz$, $f_{mod} = 0.4 kHz$, m = 30%, $T_{amb} = 25$ °C, reference point Pin 16, see figure 2, unless otherwise specified

Parameters	Test Conditions / Pin	Symbol	Min	Туре	Max	Unit
RF input voltages	(S + N)/N = 6 dB = 26 dB = 46 dB	V _{iRF}		1.5 15 150		μV
RF input for agc operation		V _{iRF}		30		μV
Control range for (Reference value $V_i = 500 \text{ mV}$)	$\Delta V_0 = 6 \text{ dB}$ $\Delta V_0 = 1 \text{ dB}$	ΔV_{iRF}		91 86		dB
Maximum RF input volt- age		V _{iRF}		0.5 0.7 0.9		V
Audio output voltage	$V_1 = 1 mV$ $V_2 = 4 \mu V, m = 0.8$	V _{0AF}		$310 (\pm 2 \text{ dB})$ $130 (\pm 3.5 \text{ dB})$		mV
RF input voltage	$V_{0AF} = 60 \text{ mV}$	V _{iRF}		5.5		μV
Total distortion of audio output voltage	$\label{eq:masser} \begin{array}{ll} m=80\%, & V_i=1\ mV\\ V_i=500\ mV \end{array}$	d		0.5 3.0		%
Signal plus noise to noise ratio of audio output voltage	$V_i = 1 mV$	$\frac{(S+N)}{N}$		50		dB
IF bandwidth (-3 dB)		B _{iF}		4.6		kHz
IF selectively	$\Delta f = \pm 9 \text{ kHz}$ $\Delta f = \pm 36 \text{ kHz}$	S _{iF}		30 60		dB



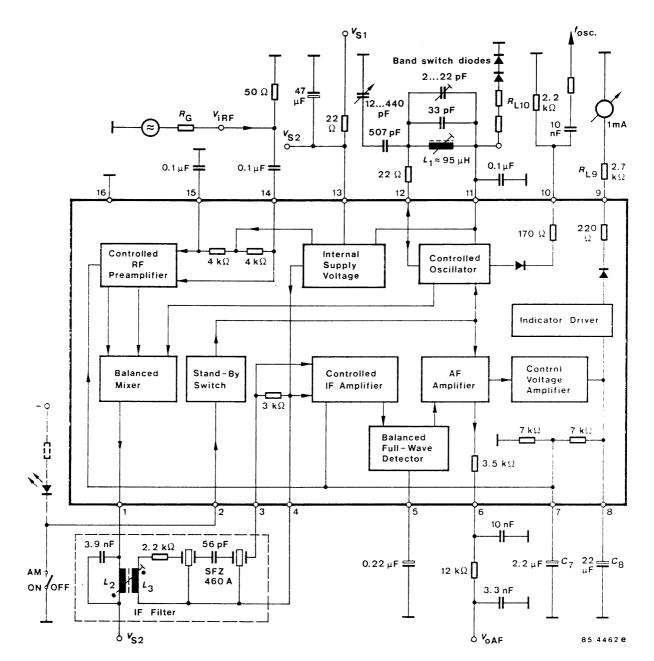
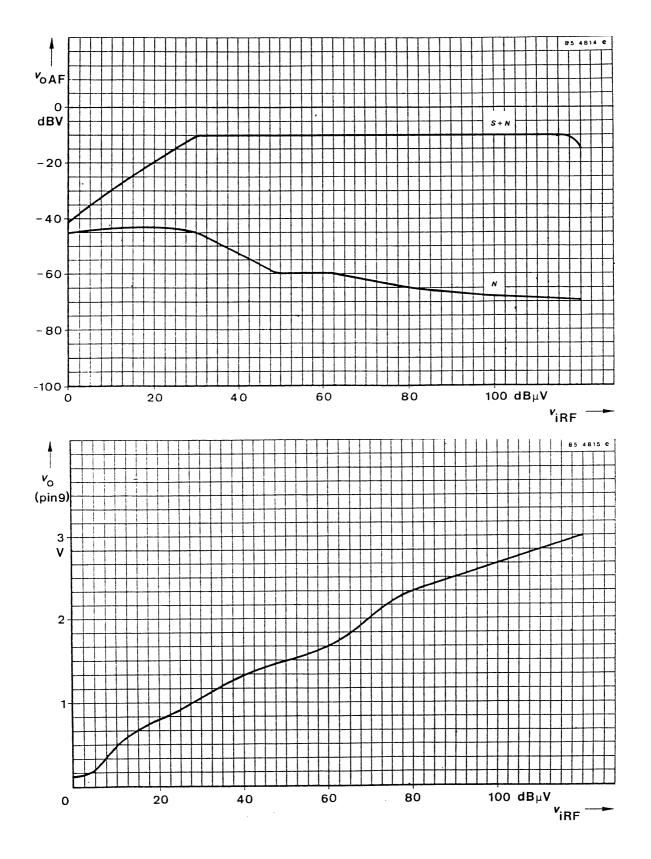


Figure 2. Test circuit

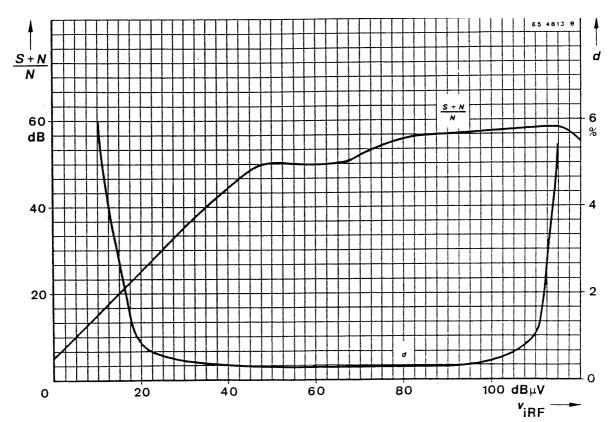


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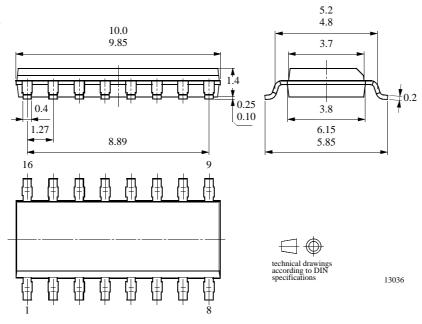






Dimensions in mm

Package SO16 Dimensions in mm



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Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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